COMPLIANT

HALOGEN

**FREE** 



## Vishay General Semiconductor

## **Ultrafast Avalanche SMD Rectifier**



**SMA (DO-214AC)** 

PRIMARY CHARACTERISTICS			
I <sub>F(AV)</sub>	1.5 A		
$V_{RRM}$	1000 V		
I <sub>FSM</sub>	30 A		
I <sub>R</sub>	5.0 μΑ		
t <sub>rr</sub>	75 ns		
$V_{F}$	1.7 V		
E <sub>R</sub>	20 mJ		
T <sub>J</sub> max.	150 °C		
Package	SMA (DO-214AC)		
Diode variations	Single		

#### **FEATURES**

- Low profile package
- Ideal for automated placement
- · Glass passivated pellet chip junction
- Low reverse current
- High reverse voltage
- Ultra fast reverse recovery time
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

#### TYPICAL APPLICATIONS

For use in high frequency rectification and freewheeling application in switching mode converters and inverters for consumer, computer, automotive, and telecommunication.

#### **MECHANICAL DATA**

Case: SMA (DO-214AC)

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Base P/NHM3\_X - halogen-free, RoHS-compliant, and AEC-Q101 qualified ("\_X" denotes revision code e.g. A, B,...)

**Terminals:** Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 and HM3 suffix meets JESD 201 class 2 whisker test

Polarity: Color band denotes the cathode end

<b>MAXIMUM RATINGS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)			
PARAMETER	SYMBOL	BYG23M	UNIT
Device marking code		BYG23M	
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	1000	V
Average forward current at T <sub>A</sub> = 65 °C	I <sub>F(AV)</sub>	1.5	А
Peak forward surge current 10 ms single half sine-wave superimposed on rated load	I <sub>FSM</sub>	I <sub>FSM</sub> 30	
Pulse energy in avalanche mode, non repetitive (inductive load switch off) $I_{(BR)R} = 1$ A, $T_J = 25$ °C	E <sub>R</sub> 20		mJ
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C



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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	BYG23M	UNIT	
Minimum breakdown voltage	I <sub>R</sub> = 100 μA		$V_{BR}$	1000	V	
Maximum instantaneous voltage	I <sub>F</sub> = 1.0 A	T <sub>J</sub> = 25 °C	V <sub>F</sub> <sup>(1)</sup>	1.7	- v	
		T <sub>J</sub> = 150 °C		1.35		
Maximum reverse current	Vp = VppM	T <sub>J</sub> = 25 °C	- I <sub>R</sub>	5	μΑ	
		T <sub>J</sub> = 125 °C		50		
Maximum reverse recovery time	I <sub>F</sub> = 0.5 A, I <sub>R</sub> =	1.0 A, I <sub>rr</sub> = 0.25 A	t <sub>rr</sub>	75	ns	

#### Note

 $^{(1)}\,$  Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)				
PARAMETER	SYMBOL	BYG23M	UNIT	
Typical thermal resistance, junction to case	R <sub>eJC</sub>	25	°C/W	
	R <sub>0JA</sub> (1)	150	°C/W	
Typical thermal resistance, junction to ambient	R <sub>0JA</sub> (2)	125		
	R <sub>0</sub> JA (3)	100		

#### Notes

- $^{(1)}$  Mounted on epoxy-glass hard tissue, 17 mm<sup>2</sup> 35  $\mu$ m Cu
- (2) Mounted on epoxy-glass hard tissue, 50 mm<sup>2</sup> 35 μm Cu
- (3) Mounted on Al-oxide-ceramic (Al<sub>2</sub>O<sub>3</sub>), 50 mm<sup>2</sup> 35 μm Cu

ORDERING INFORMATION (Example)					
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
BYG23M-M3/TR	0.064	TR	1800	7" diameter plastic tape and reel	
BYG23M-M3/TR3	0.064	TR3	7500	13" diameter plastic tape and reel	
BYG23MHM3_A/H (1)	0.064	Н	1800	7" diameter plastic tape and reel	
BYG23MHM3_A/I (1)	0.064	I	7500	13" diameter plastic tape and reel	

#### Note

(1) AEC-Q101 qualified

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### **RATINGS AND CHARACTERISTICS CURVES** (T<sub>A</sub> = 25 °C unless otherwise noted)

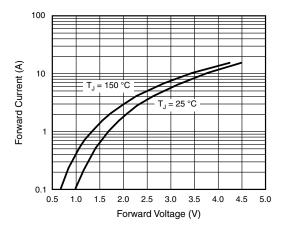


Fig. 1 - Max. Forward Current vs. Forward Voltage

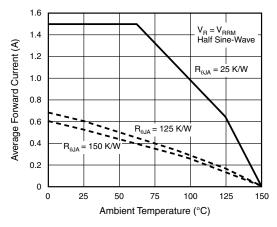


Fig. 2 - Max. Average Forward Current vs. Ambient Temperature

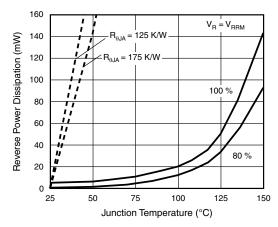


Fig. 3 - Max. Reverse Power Dissipation vs. Junction Temperature

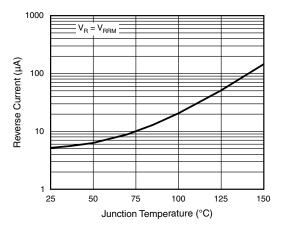


Fig. 4 - Reverse Current vs. Junction Temperature

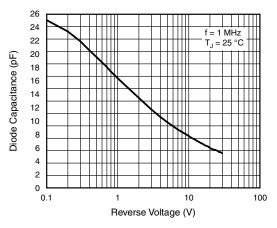


Fig. 5 - Diode Capacitance vs. Reverse Voltage



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### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)

0.194 (4.93)

#### SMA (DO-214AC) Cathode Band **Mounting Pad Layout** 0.074 (1.88) MAX. 0.066 (1.68) MIN. 0.110 (2.79) 0.065 (1.65) 0.049 (1.25) 0.100 (2.54) 0.177 (4.50) 0.157 (3.99) 0.060 (1.52) 0.012 (0.305) MIN. 0.006 (0.152) 0.208 (5.28) REF. 0.090 (2.29) 0.060 (1.52) 0.030 (0.76) 0.008 (0.203) 0 (0) 0.208 (5.28)



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